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74LCX157 Low Voltage Quad 2-Input Multiplexer with 5V Tolerant Inputs

FAIRCHILD

SEMICONDUCTOR M

74LCX157 Low Voltage Quad 2-Input Multiplexer with 5V Tolerant Inputs

General Description

The LCX157 is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (noninverted) form. The LCX157 can also be used as a function generator.

The 74LCX157 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs
- 6.5 ns t_{PD} max, 10 µA I_{CCQ} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal
- 2.0V-3.6V V_{CC} supply operation
- ±24 mA output drive
- Implements patented noise/EMI reduction circuitry
- Functionally compatible with 74 series 157
- Latch-up performance exceeds 500 mA
- ESD performance:

Human body model > 2000V Machine model > 200V

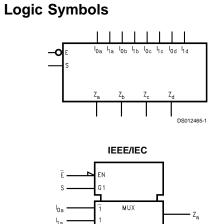
Ordering Code:

Order Number	Package Number	Package Description
74LCX157M	M16A	16-Lead (0.150" Wide) Molded Small Outline Package, SOIC, JEDEC
74LCX157SJ	M16D	16-Lead Molded Small Outline Package, SOIC EIAJ
74LCX157MTC	MTC16	16-Lead Thin Shrink Small Outline Package, TSSOP

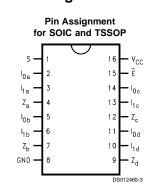
Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Z,

DS012465-2



Connection Diagram



Pin Descriptions

Pin Names	Description
I _{0a} –I _{0d}	Source 0 Data Inputs
I _{1a} –I _{1d}	Source 1 Data Inputs
E Enable Input	
S	Select Input
Z _a –Z _d	Outputs

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I_{0 b} I_{1 b} I_{0 d}

1_{1d}

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Functional Description

The LCX157 is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input (\overline{E}) is active-LOW. When \overline{E} is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The LCX157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

 $\begin{aligned} &Z_{a} = \overline{E} \cdot (I_{1a} \cdot S + I_{0a} \cdot \overline{S}) \\ &Z_{b} = \overline{E} \cdot (I_{1b} \cdot S + I_{0b} \cdot \overline{S}) \\ &Z_{c} = \overline{E} \cdot (I_{1c} \cdot S + I_{0c} \cdot \overline{S}) \\ &Z_{d} = \overline{E} \cdot (I_{1d} \cdot S + I_{0d} \cdot \overline{S}) \end{aligned}$

A common use of the LCX157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The LCX157 can generate any four of the six-

Logic Diagram

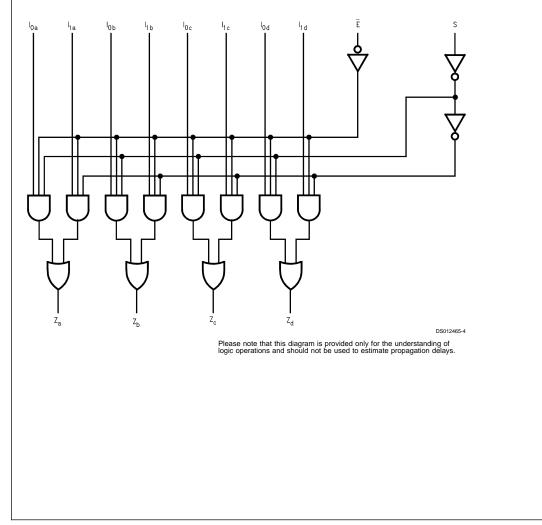
teen different functions of two variables with one variable common. This is useful for implementing gating functions.

Truth Table

	In	Outputs		
Ē	S	I ₀	I ₁	Z
Н	Х	Х	Х	L
L	н	Х	L	L
L	н	Х	н	н
L	L L	L	X	L
L	L	н	Х	н

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial



Symbol	Parameter	Value	Conditions	Units
V _{cc}	Supply Voltage	-0.5 to +7.0		V
V _I	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to V _{CC} + 0.5	Output in High or Low State (Note 2)	V
к	DC Input Diode Current	-50	V _I < GND	mA
ок	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	
0	DC Output Source/Sink Current	±50		mA
сс	DC Supply Current per Supply Pin	±100		mA
GND	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 3)

Symbol	Pa	Parameter			Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0V–3.6V		±24	mA
		V _{CC} = 2.7V		±12	
T _A	Free-Air Operating Temperatu	Free-Air Operating Temperature		85	°C
Δt/ΔV	Input Edge Rate, V _{IN} = 0.8V-	2.0V, V _{CC} = 3.0V	0	10	ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
			(V)	Min	Max	
V _{IH}	HIGH Level Input Voltage		2.7–3.6	2.0		V
V _{IL}	LOW Level Input Voltage		2.7–3.6		0.8	V
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7-3.6	V _{CC} - 0.2		V
		I _{OH} = -12 mA	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		V
		I _{OH} = -24 mA	3.0	2.2		V
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7–3.6		0.2	V
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	V
		I _{OL} = 24 mA	3.0		0.55	V
l _l	Input Leakage Current	$0 \le V_I \le 5.5V$	2.7-3.6		±5.0	μA
I _{OFF}	Power-Off Leakage Current	V _I or V _O = 5.5V	0		10	μA
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	2.7–3.6		10	μA
		$3.6V \le V_1 \le 5.5V$	2.7–3.6		±10	μA
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7-3.6		500	μA

AC Electrical Characteristics

Symbol		T	$T_A = -40^{\circ}C$ to +85°C, $C_L = 50pF$, $R_L = 500\Omega$			
	Parameter	V _{CC} = 3.	$V_{CC} = 3.3V \pm 0.3V$		V _{CC} = 2.7V	
		Min	Max	Min	Max	
t _{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	ns
t _{PLH}	S→Z _n	1.5	7.0	1.5	8.0	
t _{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	ns
t _{PLH}	$\overline{E} \rightarrow Z_n$	1.5	7.0	1.5	8.0	
t _{PHL}	Propagation Delay	1.5	5.8	1.5	6.3	ns
t _{PLH}	$I_n \rightarrow Z_n$	1.5	5.8	1.5	6.3	
t _{OSHL}	Output to Output Skew		1.0			ns
t _{OSLH}	(Note 4)		1.0			

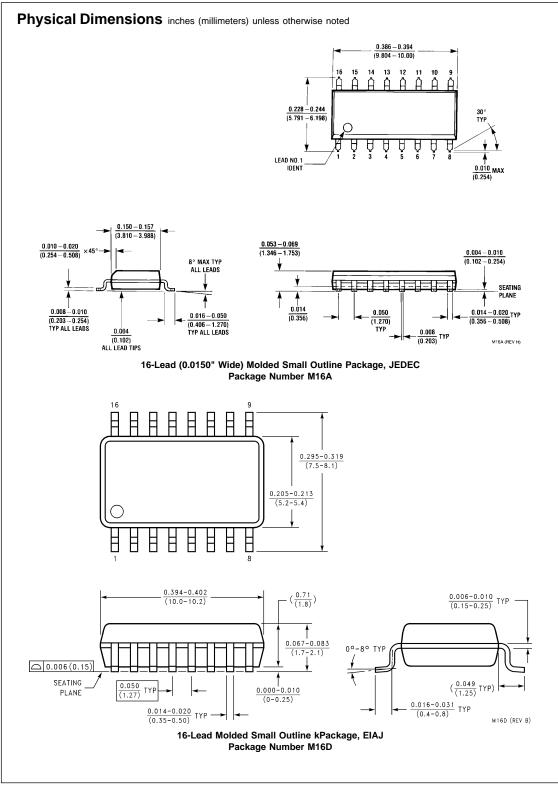
Note 4: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{cc} (V)	T _A = 25°C Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	C _L = 50 pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	C_L = 50 pF, V_{IH} = 3.3V, V_{IL} = 0V	3.3	-0.8	V

Capacitance

Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	V_{CC} = Open, V_{I} = 0V or V_{CC}	7	pF
C _{OUT}	Output Capacitance	V_{CC} = 3.3V, V_{I} = 0V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	V_{CC} = 3.3V, V_{I} = 0V or V_{CC} , f = 10 MHz	25	pF



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